



1-Megabit (32K x 8) CMOS EPROM

Features

- · Very fast read access time: (45-200 ns)
- 5V ± 10% power supply
- Capable of withstanding >2001V ESD
- · Latch-up protection up to 200 mA
- · Two line control functions to prevent bus contention
- Standard JEDEC packages
 - -32-pin PLCC
 - -28-pin TSOP
 - 28-pin, 600-mil plastic DIP
 - -32-pin, hermetic LCC
 - 28-pin, 600-mil hermetic DIP
- · Available in commercial, industrial, and military temperature ranges

Functional Description

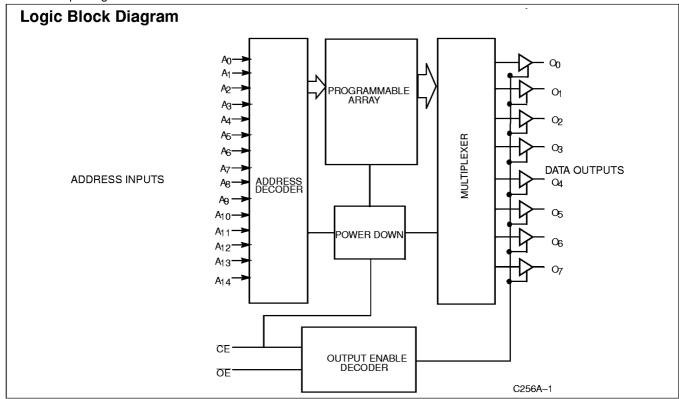
The CY27C256A is a high-performance, 256-Kbit ultraviolet erasable programmable read-only memory (EPROM) organized as 32 Kbytes by 8 bits. It is available in JEDEC-standard, one-time programmable (OTP), 32-pin PLCC and 28-pin PDIP and TSOP packages. The CY27C256A is also available in

windowed packages (28-pin hermetic DIP and 32-pin LCC) which allow the device to be erased with UV light for 100% reprogrammability.

The CY27C256A is equipped with a power-down chip enable (\overline{CE}) input and output enable (\overline{OE}) to prevent bus contention. When CE is deasserted, the device powers down to a low-power stand-by mode. The OE pin three-states the outputs without putting the device into stand-by mode. While CE offers lower power, OE provides a more rapid transition to and from three-stated outputs.

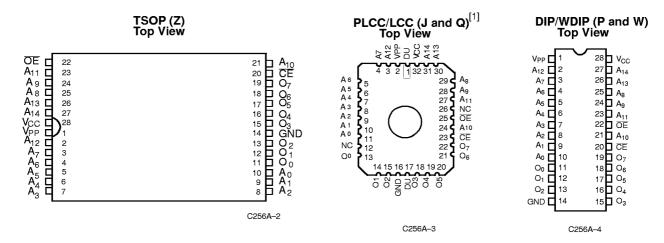
The memory cells utilize proven EPROM floating-gate technology and byte-wide intelligent programming algorithms. The EPROM cell requires only 12.75V for the supervoltage and low programming current allows for gang programming. The device allows for each memory location to be tested 100%, because each location is written to, erased, and repeatedly exercised prior to encapsulation. Each device is also tested for AC performance to guarantee that the product will meet DC and AC specification limits after customer programming.

The CY27C256A is read by asserting both the $\overline{\text{CE}}$ and the $\overline{\text{OE}}$ inputs. The contents of the memory location selected by the address on inputs A_{14} – A_0 will appear at the outputs O_7 – O_0 .





Pin Configurations



Selection Guide

		-45	-55	-70	-90	-120	-150	-200
Maximum Access Time (ns)		45	55	70	90	120	150	200
CE Access Time (ns)		45	55	70	90	120	150	200
OE Access Time (ns)		18	20	25	30	30	40	40
I _{CC} ^[2] (mA) Power Supply Current	Com'l(Max)	45	45	45	45	45	45	45
	Mil	55	55	55	55	55	55	55
I _{SB} ^[3] (mA) Stand-by Current	Com'l(Max)	15	15	15	15	15	15	15
	Mil	25	25	25	25	25	25	25

Maximum Ratings

(Above which the useful life may be guidelines, not tested.)	oe impaired. For user
Storage Temperature	65°C to +150°C
Ambient Temperature with Power Applied	55°C to +125°C
Supply Voltage to Ground Potential	0.5V to +7.0V
DC Voltage Applied to Outputs in High Z State	0.5V to +5.5V
DC Input Voltage	–3.0V to +7.0V
Transient Input Voltage	3.0V for <20 ns
DC Program Voltage	13.0 V
UV Erasure	7258 W sec/cm ²
Static Discharge Voltage(per MIL-STD-883, Method 3015)	>2001V
Latch-Up Current	>200 mA

Operating Range

Range	Ambient Temperature	V _{cc}
Commercial	0°C to +70°C	5V ± 10%
Industrial ^[4]	−40°C to +85°C	5V ± 10%
Military ^[5]	−55°C to +125°C	5V ± 10%

Notes:

- For LCC/PLCC only: Pins 1 and 17 are designated as DU (DON'T USE) and should not be used.

- $\begin{array}{l} V_{CC} = \text{Max., } I_{OUT} = 0 \text{ mA, f=5 MHz.} \\ V_{CC} = \text{Max., } \overrightarrow{CE} = V_{IH}. \\ \text{Contact a Cypress representative for industrial temperature range} \end{array}$ 4. specification.
 T_A is the "instant on" case temperature.



DC Electrical Characteristics Over the Operating Range^[6,7]

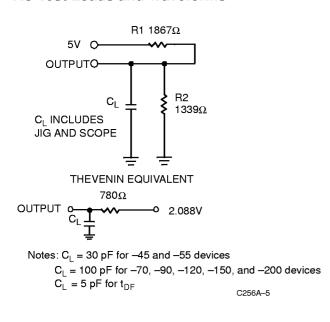
Parameter	Description	Test Condition	Min.	Max.	Unit	
V _{OH}	Output HIGH Voltage	$V_{CC} = Min., I_{OH} = -400 \mu A$		2.4		٧
V _{OL}	Output LOW Voltage	V _{CC} = Min., I _{OL} = 2 mA			0.45	٧
V _{IH}	Input HIGH Level	Guaranteed Input Logical HIG Voltage for All Inputs	2.0	V _{CC} +0.5	V	
V _{IL}	Input LOW Level	Guaranteed Input Logical LOV Voltage for All Inputs		0.8	V	
l _{LI}	Input Leakage Current	$GND \leq V_{IN} \leq V_{CC}$		-10	+10	μΑ
I _{LO}	Output Leakage Current	$GND \le V_{OUT} \le V_{CC}$, Output D	isable	-10	+10	μΑ
Icc	Power Supply Current	V _{CC} =Max., I _{OUT} =0 mA,	Com'l		45	mA
		f=5 MHz	Mil		55	mA
I _{SB}	Stand-By Current	V _{CC} =Max., CE = V _{IH}	Com'l		15	mA
			Mil		25	mA

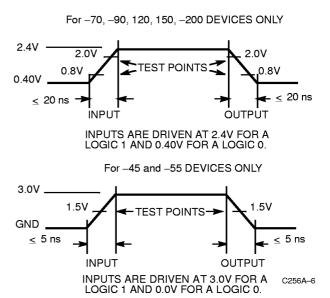
Capacitance^[8]

Parameter	Description	Test Conditions	Max	Unit
C _{IN}	Input Capacitance	$T_A = 25^{\circ}C, f = 1 \text{ MHz},$	10	pF
C _{OUT}	Output Capacitance	$V_{CC} = 5.0V$	12	pF

- See the last page of this specification for Group A subgroup testing information. See Introduction to CMOS NVMs in this Data Book for general information on testing. 6. 7. 8.
- This parameter is sampled only and is not 100% tested.

AC Test Loads and Waveforms



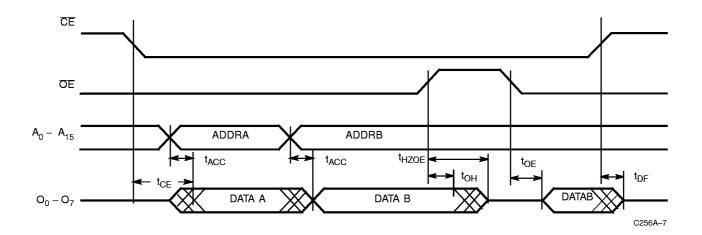




Switching Characteristics Over the Operating Range

			45	-:	55	_	70	_!	90	-1	20	-1	50	-2	200	
Parameter	Description	Min	Max	Min	Мах	Min	Мах	Unit								
t _{ACC}	Address to Output Valid		45		55		70		90		120		150		200	ns
t _{HZOE}	Output Enable In- active to High Z		20		20		25		25		30		30		30	ns
t _{OE}	OE Active to Output Valid		18		20		25		30		30		40		40	ns
t _{DF} ^[8]	OE or CE Inactive to High Z, which- ever occurs first		25		25		25		30		30		30		30	ns
t _{CE}	CE Active to Output Valid		45		55		70		90		120		150		200	ns
t _{OH}	Output Data Hold	0		0		0		0		0		0		0		ns

Switching Waveform



Erasure Characteristics

Wavelengths of light less than 4000 Angstroms begin to erase the CY27C256A in the windowed package. For this reason, an opaque label should be placed over the window if the EPROM is exposed to sunlight or fluorescent lighting for extended periods of time.

The recommended dose of ultraviolet light for erasure is a wavelength of 2537 Angstroms for a minimum dose (UV intensity multiplied by exposure time) of 15 Wsec/cm². For an ultraviolet lamp with a 12 mW/cm² power rating, the exposure time would be approximately 15 minutes. The CY27C256A

needs to be within 1 inch of the lamp during erasure. Permanent damage may result if the EPROM is exposed to high-intensity UV light for an extended period of time. 7258 Wsec/cm² is the recommended maximum dosage.

Programming Modes

Programming support is available from Cypress as well as from a number of third-party software vendors. For detailed programming information, including a listing of software packages, please see the PROM Programming Information located at the end of this section. Programming algorithms can be obtained from any Cypress representative.



Table 1. Programming Electrical Characteristics

Parameter	Description	Min.	Max.	Unit
V _{PP}	Programming Power Supply	12.5	13	٧
Грр	Programming Supply Current		50	mA
V _{IHP}	Programming Input Voltage HIGH	3.0	V _{CC}	V
V _{ILP}	Programming Input Voltage LOW	-0.5	0.4	V
V _{CCP}	Programming V _{CC}	6.0	6.5	V

Table 2. Mode Selection

		Pin Function ^[9]							
Mode	CE	ŌĒ	V _{PP}	A ₀	A ₉	Outputs			
Read	V _{IL}	V _{IL}	V _{CC}	A ₀	A ₉	Dout			
Output Disable	V _{IL}	V _{IH}	V _{CC}	Х	Х	High Z			
Stand-by(TTL)	V _{IH}	Х	V _{CC}	Х	Х	High Z			
Program	V _{ILP}	V _{IHP}	V _{PP}	A ₀	A ₉	Din			
Program Verify	V _{IHP}	V _{ILP}	V _{PP}	A ₀	A ₉	Dout			
Program Inhibit	V _{IHP}	V _{IHP}	V _{PP}	Х	Х	High Z			
Signature Read (MFG) ^[11]	V _{IL}	V _{IL}	V _{CC}	V _{IL}	V _{HV} ^[10]	34H			
Signature Read (DEV) ^[11]	V _{IL}	V _{IL}	V _{CC}	V _{IH}	V _{HV} ^[10]	1FH			

Notes:

9. X can be V_{IL} or V_{IH}
10. V_{HV}=12V±0.5V
11. A₁ - A₈ and A₁₀ - A₁₄ = V_{IL}



Ordering Information^[12]

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
45	CY27C256A-45JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C256A-45PC	P15	28-Lead (600-Mil) Molded DIP	
	CY27C256A-45WC	W16	28-Lead (600-Mil) Windowed CerDIP	
	CY27C256A-45ZC	Z28	28-Lead Thin Small Outline Package	
	CY27C256A-45QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	Military
	CY27C256A-45WMB	W16	28-Lead (600-Mil) Windowed CerDIP	
55	CY27C256A-55JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C256A-55PC	P15	28-Lead (600-Mil) Molded DIP	
	CY27C256A-55WC	W16	28-Lead (600-Mil) Windowed CerDIP	
	CY27C256A-55ZC	Z28	28-Lead Thin Small Outline Package	
	CY27C256A-55QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	Military
	CY27C256A-55WMB	W16	28-Lead (600-Mil) Windowed CerDIP	-
70	CY27C256A-70JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C256A-70PC	P15	28-Lead (600-Mil) Molded DIP	-
	CY27C256A-70WC	W16	28-Lead (600-Mil) Windowed CerDIP	-
	CY27C256A-70ZC	Z28	28-Lead Thin Small Outline Package	•
	CY27C256A-70QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	Military
	CY27C256A-70WMB	W16	28-Lead (600-Mil) Windowed CerDIP	•
90	CY27C256A-90JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C256A-90PC	P15	28-Lead (600-Mil) Molded DIP	-
	CY27C256A-90WC	W16	28-Lead (600-Mil) Windowed CerDIP	
	CY27C256A-90ZC	Z28	28-Lead Thin Small Outline Package	-
	CY27C256A-90QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	Military
	CY27C256A-90WMB	W16	28-Lead (600-Mil) Windowed CerDIP	
120	CY27C256A-120JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C256A-120PC	P15	28-Lead (600-Mil) Molded DIP	-
	CY27C256A-120WC	W16	28-Lead (600-Mil) Windowed CerDIP	-
	CY27C256A-120ZC	Z28	28-Lead Thin Small Outline Package	
	CY27C256A-120QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	Military
	CY27C256A-120WMB	W16	28-Lead (600-Mil) Windowed CerDIP	
150	CY27C256A-150JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C256A-150PC	P15	28-Lead (600-Mil) Molded DIP	
	CY27C256A-150WC	W16	28-Lead (600-Mil) Windowed CerDIP	1
	CY27C256A-150ZC	Z28	28-Lead Thin Small Outline Package	1
	CY27C256A-150QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	Military
	CY27C256A-150WMB	W16	28-Lead (600-Mil) Windowed CerDIP	-



Ordering Information^[12] (continued)

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
200	CY27C256A-200JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C256A-200PC	P15	28-Lead (600-Mil) Molded DIP	
	CY27C256A-200WC	W16	28-Lead (600-Mil) Windowed CerDIP	
	CY27C256A-200ZC	Z28	28-Lead Thin Small Outline Package	
	CY27C256A-200QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	Military
	CY27C256A-200WMB	W16	28-Lead (600-Mil) Windowed CerDIP	

Note:

MILITARY SPECIFICATIONS Group A Subgroup Testing

DC Characteristics

Parameter	Subgroups
V _{OH}	1, 2, 3
V _{OL}	1, 2, 3
V _{IH}	1, 2, 3
V _{IL}	1, 2, 3
ILI	1, 2, 3
I _{LO}	1, 2, 3
Icc	1, 2, 3
I _{SB}	1, 2, 3

Switching Characteristics

Parameter	Subgroups
t _{ACC}	7, 8, 9, 10, 11
t _{OE}	7, 8, 9, 10, 11
t _{CE}	7, 8, 9, 10, 11

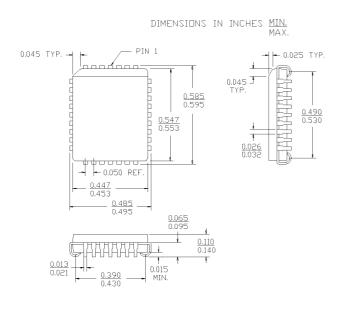
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^{12.} Contact a Cypress sales representative for industrial temperature offerings.



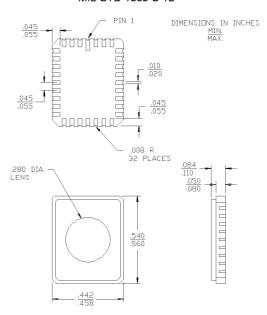
Package Diagrams

32-Lead Plastic Leaded Chip Carrier J65

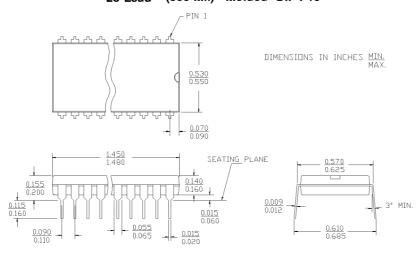


32-Pin Windowed Rectangular Leadless Chip Carrier Q55

. MIL-STD-1835 C-12



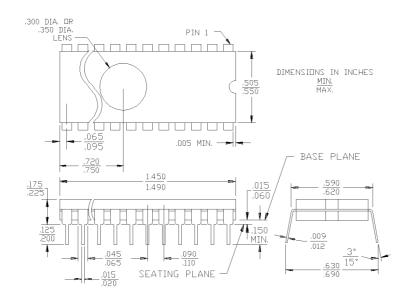
28-Lead (600-Mil) Molded DIP P15



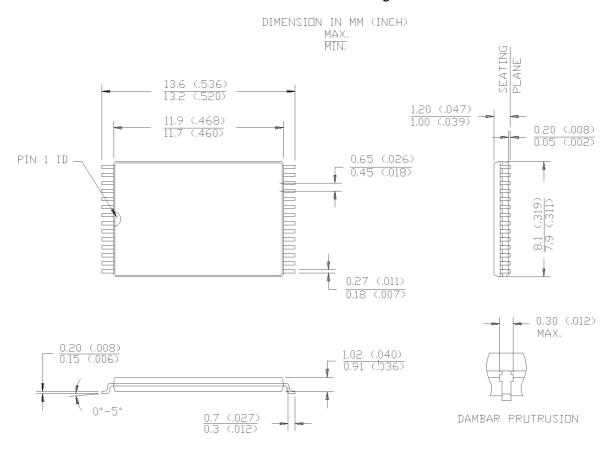


Package Diagrams (continued)

28-Lead (600-Mil) Windowed CerDIP W16 MIL-STD-1835 D-10 Config.A



28-Lead Thin Small Outline Package Z28



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